Search Notes



Application/Control No.	Applicant(s)/Patent Under Reexamination
10575489	FUKSHIMA ET AL.
Examiner	Art Unit
Yang, Minchul	2891

Class	Subclass	Date	Examiner
216	24, 41	8/30/2007	RTC
257	25, 81, 91, 95, 98-100, 103	8/30/2007	RTC
438	22, 46, 47, 918, 9	8/30/2007	RTC
updated		4/22/2008	my
updated		12/3/2008	my
none		7/2/2009	my
438	22,26,47	11/23/2009	my
257	E21.499, E21.502, E21.503	11/23/2009	my

\sim \sim		\sim 1 I	110	TEA
~ <u>_</u>	$\Lambda \boldsymbol{\nu}$	" (NIT	TES
~ > 1	-		14.	<i>,</i> , , , ,

Search Notes	Date	Examiner
Fukshima Kubo Inoue Tanaka Masui Matsui	8/30/2007	RTC
((257/98-100).ccls. (257/91).ccls. (257/103).ccls. (257/95).ccls.	8/30/2007	RTC
(216/24).ccls. (216/41).ccls. (438/22).ccls. (438/46-47).ccls.) and ((light-		
emitting lightemitting light adj emitting)adj diode and (enhance\$3 with light		
with extract\$4) and ((rough\$3 adj surface adj structure) (rough\$3 adj		
interface) (interfac\$2 with textur\$3) (random\$3 adj grat\$3 adj structure)		
(protrusion\$2 same cones with pyramid\$4) (order\$2 with textur\$3 with		
interface) (textur\$3 adj (photoresist photo-resist photo adj resist		
((light-emitting lightemitting light adj emitting)adj diode and (silicon with	8/30/2007	RTC
organi\$3 with solven\$3)).bi.		
((light-emitting lightemitting light adj emitting)adj diode and (silicon with	8/30/2007	RTC
organi\$3 with solven\$3) and (silicon adj alkoxide TMOS TEOS)).bi.		
updated	4/22/2008	my
updated	12/3/2008	my
none	7/2/2009	my
updated	11/23/2009	my

INTERFERENCE SEARCH

Class	Subclass	Date	Examiner
438	22,26,47	11/23/2009	my
257	E21.499, E21.502, E21.503	11/23/2009	my

U.S. Patent and Trademark Office Part of Paper No.: 20091123